NSN 5961-00-415-6613

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Inclosure Material:

Metal

Overall Length:

0.410 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 forward voltage, average and 100.0 reverse voltage, average

Current Rating Per Characteristic:

25.00 amperes forward current, average

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnpn

Terminal Type And Quantity:

1 case and 2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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